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Metallic vs. Semiconducting Single-Walled Carbon Nanotube Separation Using Dielectrophoresis

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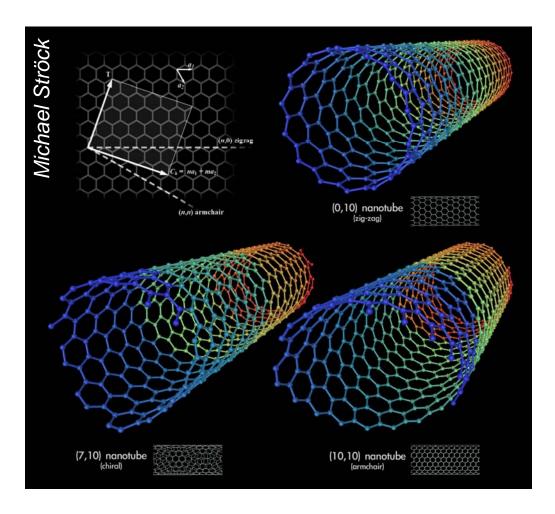
OUTLINE

RICE

- BACKGROUND
 - Current type separation methods
 - What is dielectrophoresis (DEP)
- * THEORETICAL PRINCIPLES
 - Clausius-Mossotti factor
 - Coaxial channel geometry
 - Governing equations: forces & torques
- BROWNIAN DYNAMICS SIMULATIONS
 - Rotational Phase Diagram
 - Device Performance
 - Effect of Ensemble Size
 - Optimization with Simplex Method
- EXPERIMENTAL RESULTS
 - Measuring Type Enrichment
 - Results with Pluronic Decants
 - Studying the Surfactant Effect
 - Mixtures of Anionic and Cationic Surfactants
- ***** CONCLUSIONS
- * ACKNOWLEDGEMENTS

SWNT ARE A CLASS OF MOLECULES





Chirality (n,m) identifies the species

(n,0) and (0,m): zig-zag

(n,n): armchair

(n,m): chiral

- •Metallic: n = m (bandgap = 0 eV)
- •Semi-metallic: n m is multiple of 3 ("mod 3 tubes," bandgap ~1-10 meV)
- •Semiconducting: n m is not a multiple of 3 (bandgap ~0.5 1.0 eV; HiPco 0.8-1.4 eV)
- Current methods produce mixtures of metallic/semi-metallic (1/3rd) and semiconductors (2/3rd)
- * Different diameters, polydisperse length

CURRENT TYPE SEPARATION METHODS



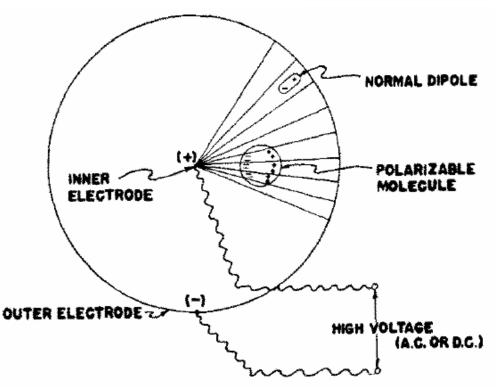
- Covalent functionalization Strano et al., Science 2003
- Selective adsorption Chattopadhryay et al., JACS 2003
- Ion exchange chromatography Zheng et al., Science 2003
- Selective elimination by electrical breakdown Collins et al., Science 2001
- Density gradient ultracentifugation Arnold et al., Nature Nanotech. 2006
- Electrophoresis Heller et al., JACS 2004
- Dielectrophoresis Krupke et al., Science 2003

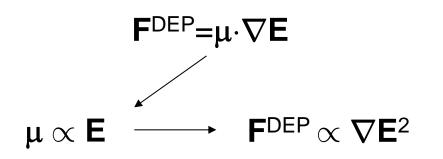
So far, all methods yield small quantities of SWNTs (mg) Some may be scalable: modeling can help scale-up

WHAT IS DIELECTROPHORESIS (DEP)



- Motion of particles caused by polarization effects in a Nonuniform Electric Field
- The direction of motion is independent of the field direction
- For the same field, metallic particles have an higher dipole moment than semiconducting ones



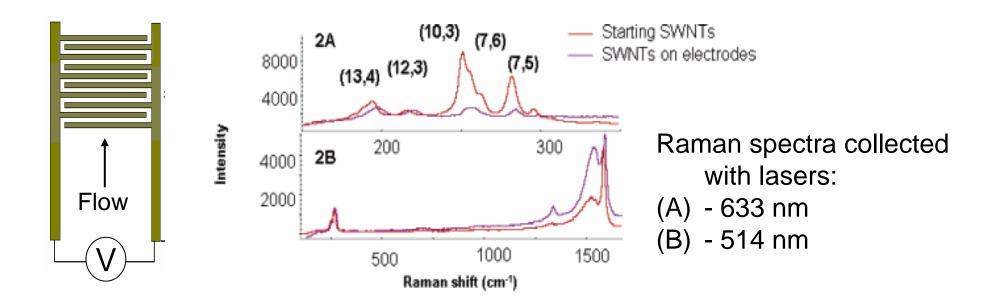


Ref: Pohl, J.A.P. 1958

PREVIOUS DEP SEPARATION

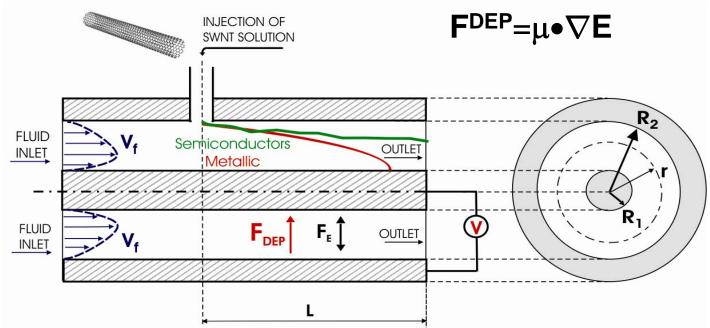


- Ralph Krupke et al. Science 2003 First work on metallic vs. semiconductors DEP separation with a drop of solution placed on an interdigitated electrode array
- * Kim et al. J. Phys. Chem. B, 2006 (Strano) Used the same method as Krupke but with mixtures of anionic and cationic surfactants (main results are shown later)
- Haiqing Peng et al. JACS, 2006 (@ Rice) Extended Krupke's method for higher throughput using DEP-Field Flow Fractionation (DEP-FFF):



COAXIAL CHANNEL GEOMETRY





* Advantages of Coaxial Geometry:

- ♣ F^{DEP} scales with 1/r³ like in interdigitated electrodes; no regions with F^{DEP}=0
- Analytical expression for flow and DEP fields and forces
- No need for microfabrication

Spatial Scaling of Electric Forces:

$$\mathbf{F}^{\text{DEP}} \propto \mathbf{\nabla E}^2 \propto V_{AC}^2/r^3$$
 $\mathbf{F}^{\text{E}} \propto \mathbf{E} \propto V_{DC}/r$

* A small Electrophoretic force **F**^E prevents the *Semiconducting SWNTs* from diffusing to the outer radius R₂, making them remain in solution

SWNTs EQUATIONS MOTION



$$0 = F^T + F^{Hydro} + F^{Brown}$$

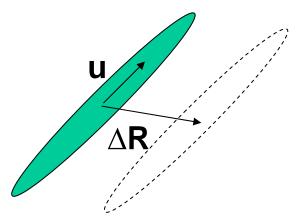
Same for Torques

- Inertia neglected: small SWNT mass; acceleration time scale (ps) << viscous scale</p>
- Brownian forces are important: stochastic differential Eq. Brownian Dynamics
 Algorithm with Forward Euler scheme to integrate eqs. of motion
- Optimal Parameters for Cylinders radius, Voltage and Flow determined

$$\mathbf{u}(t + \Delta t) - \mathbf{u}(t) = \frac{D^R}{K_B T} \mathbf{M}_T \times \mathbf{u}(t) \Delta t + \Delta t (\underline{\mathbf{k}} \cdot \mathbf{u} - \mathbf{u}(\mathbf{u}\mathbf{u} : \underline{\mathbf{k}})) + \hat{\beta}(t)$$

$$\underline{\mathbf{k}} = \nabla \mathbf{v_f}$$

$$< \hat{\beta}(t) \hat{\beta}(t) >= 2D^R (\underline{\mathbf{I}} - \mathbf{u}\mathbf{u}) \Delta t$$



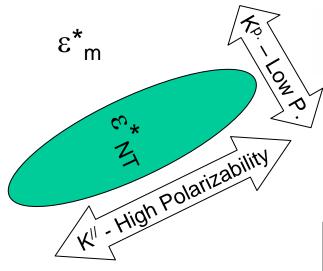
$$\mathbf{R}(t + \Delta t) - \mathbf{R}(t) = \frac{\Delta t}{K_B T} \underline{\underline{\mathbf{D}}} \cdot \mathbf{F}_T + \mathbf{v}_f \Delta t + \mathbf{b}(t)$$

$$< \mathbf{b}(t)\mathbf{b}(t) >= 2\underline{\mathbf{D}}\Delta t$$

Ref: Hartmut Lowen, Phys. Rev. E, 1994

CLAUSIUS-MOSSOTTI FACTOR





$$<\mathbf{M^E}> = V_{NT}\epsilon_m Re\left[K^{//}K^{\perp}\right](L^{\perp} - L^{//})E_{RMS}^2(\mathbf{u} \cdot \mathbf{r})(\mathbf{u} \times \mathbf{r})$$

$$\mathbf{F}^{DEP} = \frac{V_{NT}}{2} \epsilon_m Re\left[K\right] \nabla E^2$$

$$\epsilon^*$$
 – Dielectric Constant

$$\varepsilon$$
 – Permittivity

$$\sigma$$
 – Conductivity

$$\epsilon^* = \epsilon - i \frac{\sigma}{2\pi f}$$

$$K^{\perp,\parallel} = \frac{\epsilon_{NT}^* - \epsilon_m^*}{\epsilon_m^* + (\epsilon_{NT}^* - \epsilon_m^*)L^{\perp,\parallel}}$$

- SWNTs modeled as prolate ellipsoids to compute depolarization factors L
- * For frequencies f ~ MHz, K_M remains constant $(K_M^{\prime\prime} \sim 10^4)$; K_S can change several orders of magnitude
- Separation efficiency is chiefly controlled by the Polarization ratio set by selecting f in the MHz range:

$$P(f) = Re[K_M^{\parallel}]/Re[K_S^{\parallel}]$$

Ref: Ralph Krupke et al. Nano Lett., 2004



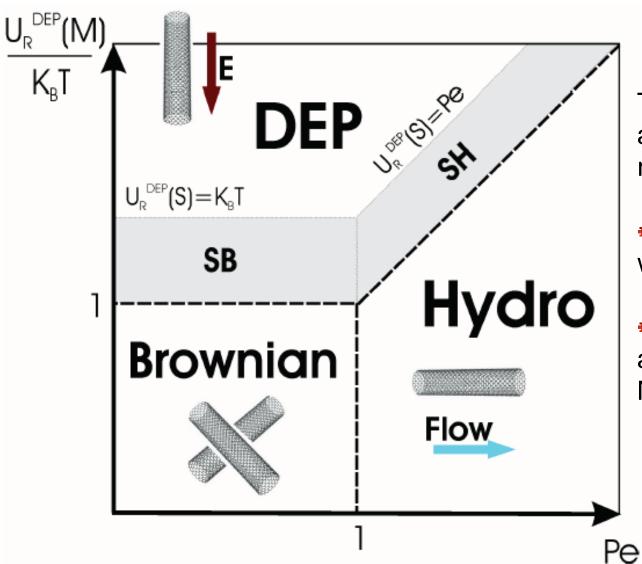
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- *** BROWNIAN DYNAMICS SIMULATIONS**
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ROTATIONAL PHASE DIAGRAM



$$0 = F^{DEP} + F^{Hydro} + F^{Brown}$$

$$0 = M^{DEP} + M^{Hydro} + M^{Brown}$$



The two shaded areas are the preferential regimes for separation:

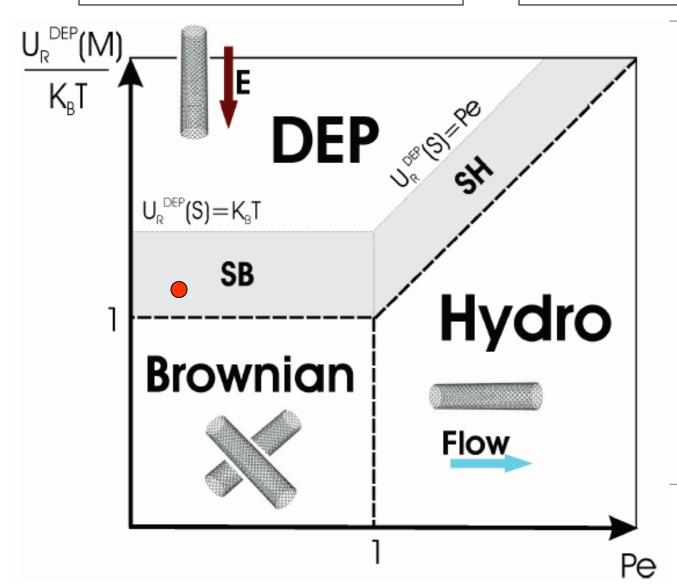
- SB Only Metals align with field
- SH Semiconductors align with flow and Metals with field

ROTATIONAL PHASE DIAGRAM



$$0 = F^{DEP} + F^{Hydro} + F^{Brown}$$

$$0 = M^{DEP} + M^{Hydro} + M^{Brown}$$



$$\frac{R_2}{l^p} = 10^3$$

$$\frac{U_R^{DEP}(M, R_2)}{K_B T} = 10$$

$$\frac{T^{DEP}(R_2 \to R_1)}{T^{BM}(R_2 \to R_1)} = 0.1$$

$$Pe(R_1) = \frac{\frac{\partial v_f}{\partial r}|_{R_1}}{D^R} = 0.01$$

$$\frac{M_M^{DEP}(R_2)}{M^{Hydro}(R_2)} = 1551.3$$

LENGTH DISTRIBUTION

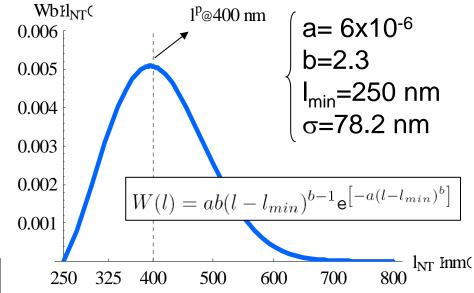


- Fixed uniform radius r_{NT}=0.5 nm
- I_{NT} = random number following aWeibull (W) distribution
- The parameters for the distribution were chosen so that:

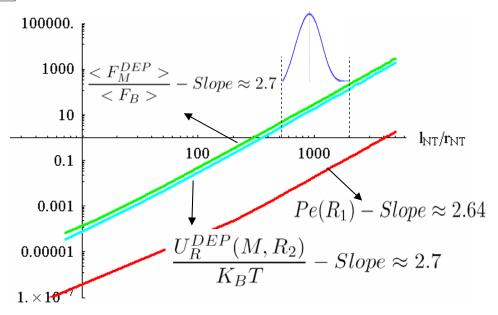
$$\frac{U_R^{DEP}(M, R_2, l_{min})}{K_B T} > 2$$

$$\left(\frac{< l > +2\sigma}{l_{min}}\right)^{2.7} < 10$$

- Represent length distribution of HiPco SWNTs subjected to a length sorting technique: Becker et al.(NIST) Adv. Mater. 2007
- In the regime where DEP and Hydro dominate the <u>SWNT alignment</u> is practically length independent



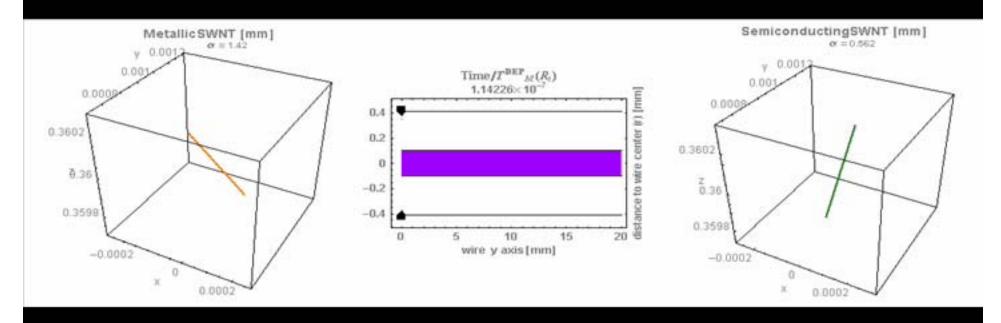
Ref: Shiren Wang et al. Nanotechnology, 2003



MOTION OF SWNTs IN DEVICE: DEP + EP



Separation trailer with 6 metals (red) and 6 semiconductors (green)



Side boxes show the orientation of one of the SWNTs S_{MS} =10 , Fixed length I_{NT} =400 nm

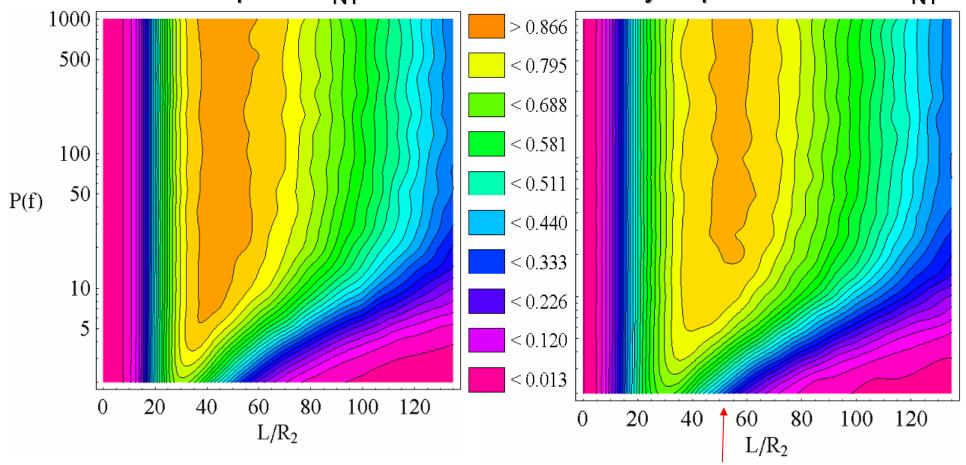
DEVICE PERFORMANCE (P): DEP + EP



Independent of initial fraction of injected semiconductors versus injected metals

$$P = rac{N_M^{col.}}{N_M^{inj.}} rac{N_S^{sol.}}{N_S^{inj.}}$$

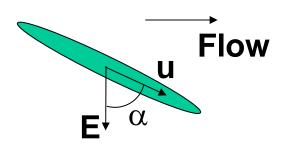




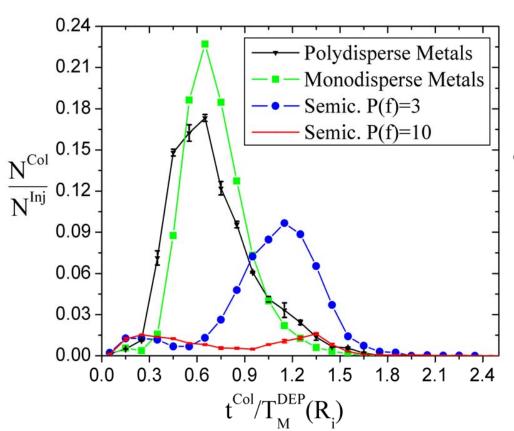
Best Length L=54.2R₂

EFFECT OF ENSEMBLE SIZE: DEP + EP

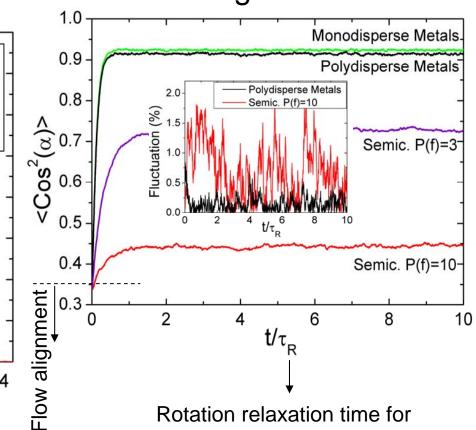
- Results with best Channel Length L=54.2R₂
- The small error values shown for Metals and Semiconductors w/ S_{MS}=10 in both plots indicate that the number of particles used is high enough



Histogram of Collected SWNTS



Average Orientation



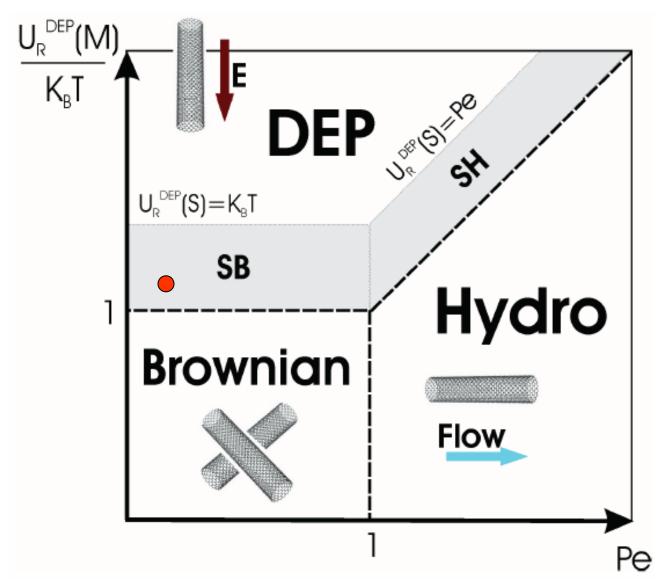
Rotation relaxation time for Monodispersed length tubes

PHASE DIAGRAM AND OPTIMIZATION



$$0 = F^{DEP} + F^{Hydro} + F^{Brown}$$

$$0 = M^{DEP} + M^{Hydro} + M^{Brown}$$



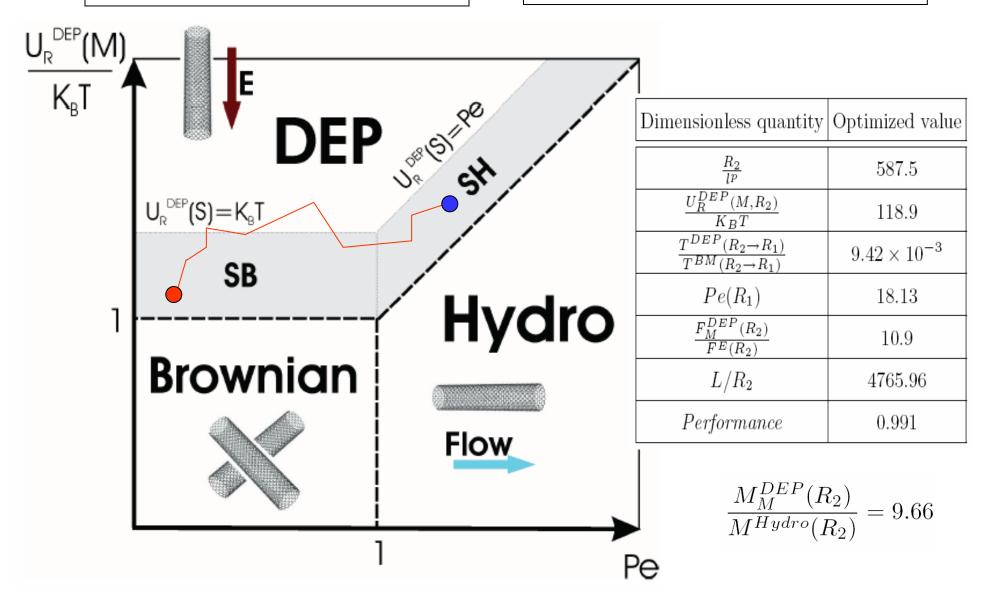
Optimal conditions obtained w/ a Nelder and Mead direct search algorithm. This iteratively searches for the maximum in separation performance as a function of the device parameters

PHASE DIAGRAM AND OPTIMIZATION



$$0 = F^{DEP} + F^{Hydro} + F^{Brown}$$

$$0 = M^{DEP} + M^{Hydro} + M^{Brown}$$

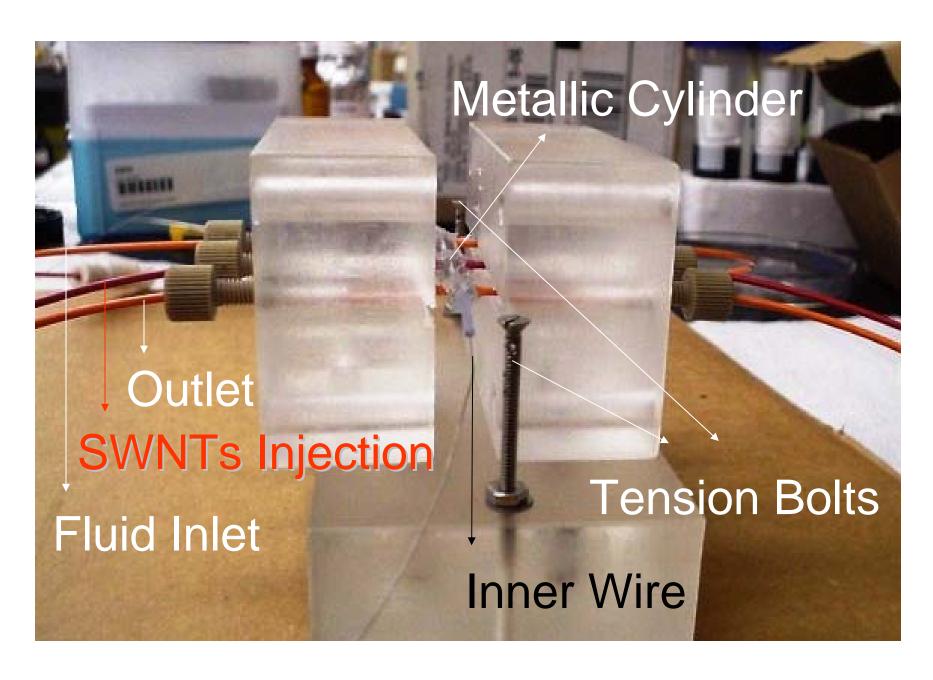




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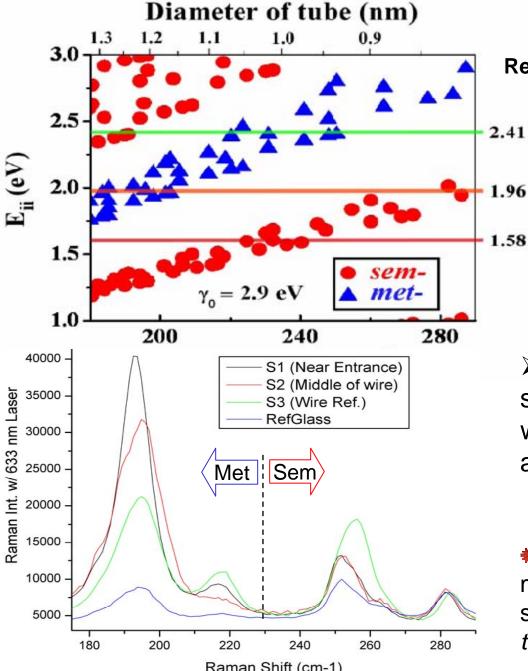
THE DEP SEPARATION DEVICE





MEASURING TYPE ENRICHMENT





Ref: H. Kataura et al. Synthetic Metals, 1999

 $\lambda = 514.5 \text{ nm}$

7. 62 116 11

1.96 λ =633 nm

 $\lambda = 785 \text{ nm}$

Example with 633 laser:

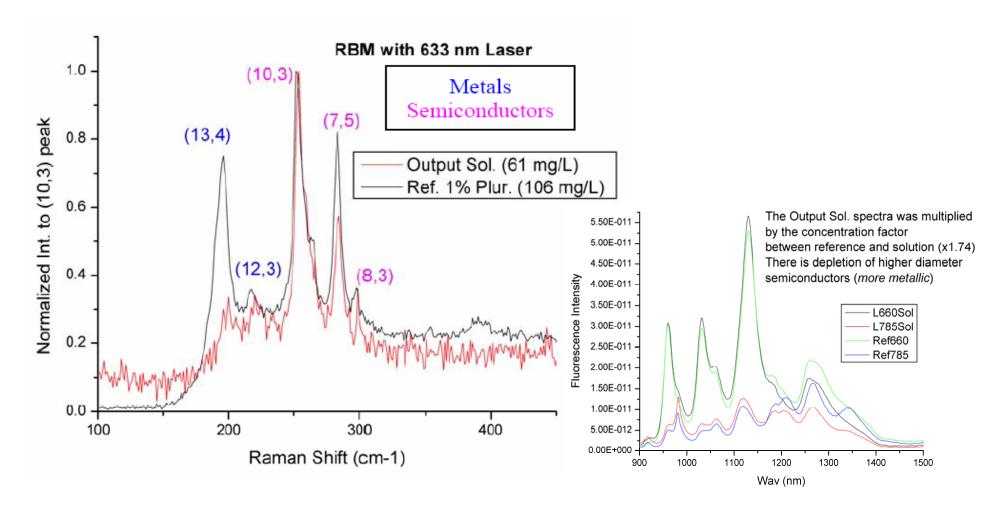
- The *peaks relative intensity* show that mostly Metallic tubes were collected at different spots along the wire
- * Liquid Phase Raman is currently the most accurate method for measuring separation. Solid phase can be troublesome

OUTPUT SOLUTION ANALYSIS



- Simple test with a single flow using a 1% Pluronic (F108) decant
- *F* = 42 MHz

- Initial sol. Conc.= 106 mg/L
- Eluate conc.= 61 mg/L
- Eluate mostly has semiconductors
- * ~ 40% SWNTs collected on wire



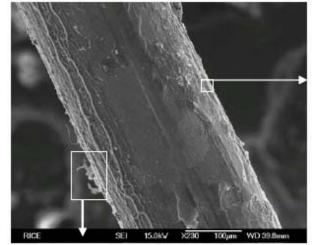
LOOKING AT THE WIRE

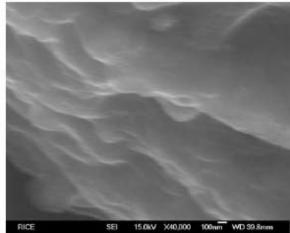


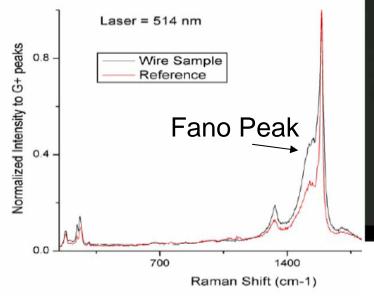
The wire gets covered with a foam of SWNTs + surfactant with a density

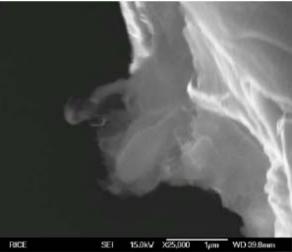
of $\sim 20 \text{ mg/cm}^2$

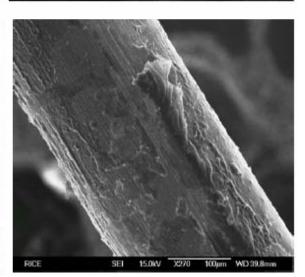
The Fano peak relative increase in 514 Raman indicates metallic enrichment







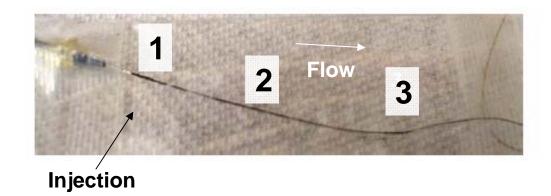


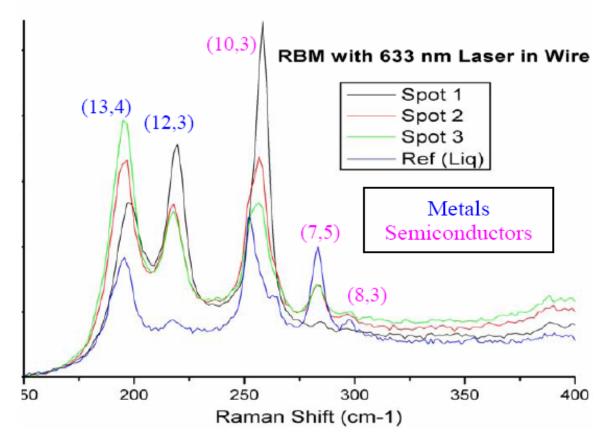


SEM by Laura McJilton

LOOKING AT THE WIRE







- ➤ Total Length = 50 mm
- ➤ Diameter = 0.254 mm
 - Metallic enrichment can be measured by the relative intensities of the (13,4) and (10,3) peaks in 633 Raman
 - * Spot 1 is at the injection, so it collected a big agglomerate of all kinds of SWNTs (taken as reference)
 - Spots 2 and 3 along the wire are metallic enriched

OUTPUT AND WIRE TESTS

Eluate

Semiconductors

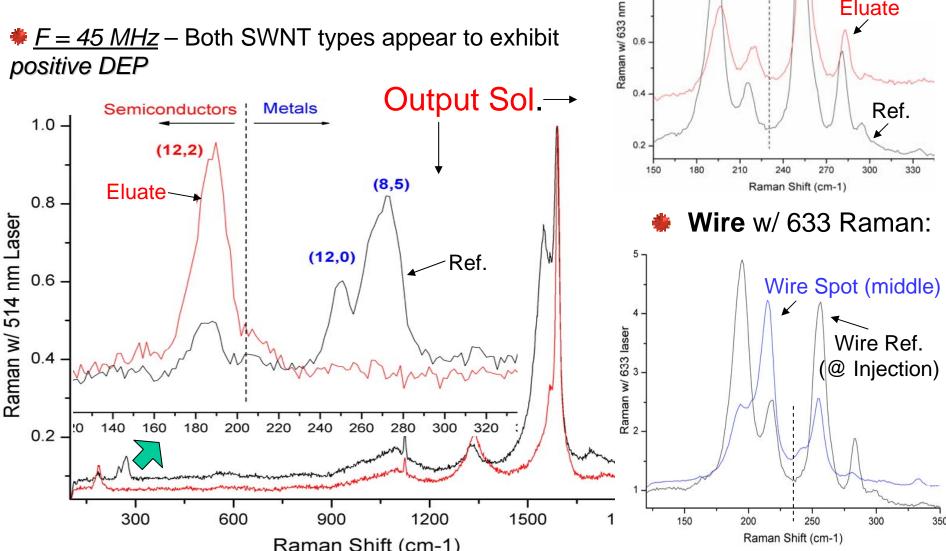
Metals

1.0 4

8.0

* Single solution flow (1% Pluronic) using smaller cylinder and wire dimensions. Significant enrichment measured with 514 laser

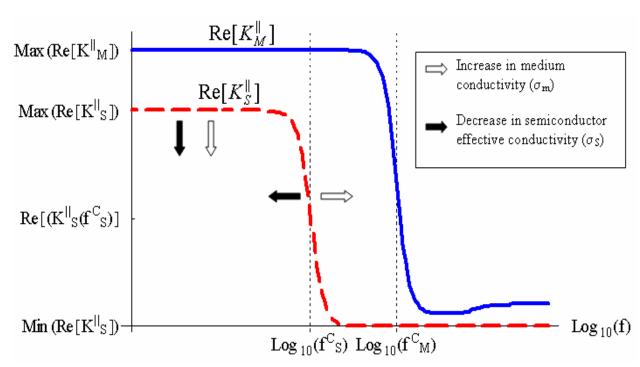
F = 45 MHz – Both SWNT types appear to exhibit



STUDYING THE EFFECT OF SURFACTANT

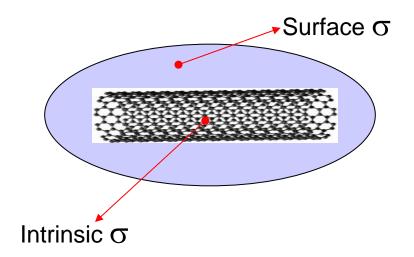


- The SWNT effective conductivity (σ_{eff}) as seen by the medium is the main physical property that enables type separation
- This quantity is composed of two components:



 $\sigma_{\text{eff}} = F (Surface \sigma, Intrinsic \sigma)$

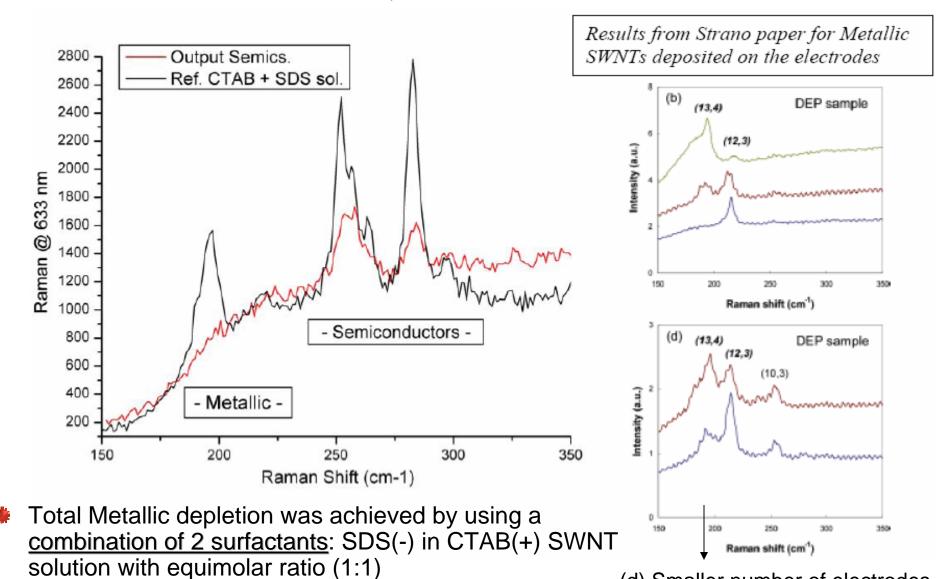
ightharpoonup It should be possible to tune σ_{eff} by changing the surfactant layer conductivity



COMPARISON WITH STRANO et al. WORK USING A CTAB+SDS EQUIMOLAR MIXTURE

SWNTs flocculated due to heating





Ref: Kim et al. J. Phys. Chem. B, 2006

(d) Smaller number of electrodes

CONCLUSIONS



- Model is in dimensionless variables; can be converted into dimensional parameters once the properties of liquid, surfactant, and SWNTs (metallic & semiconducting) are determined
- * A 99.1% sorting performance can be achieved at optimal conditions if:
 - No short tubes (below ~250 nm) are present and the length distribution is narrow (standard deviation ~ 78 nm). This can be obtained using length sorted or carpet grown SWNTs.
 - The polarization ratio P(f) is 10 or higher (at least one order of magnitude difference between the DEP force on metals and the one on semiconductors)
- Experimental tests show good separation at a frequency of 45 MHz either by:
 - Using a non-ionic surfactant (Pluoronic F108)
 - Or an equimolar mixture of a Cationic and Anionic surfactant (CTAB:SDS)
- Once optimal surfactant is determined, we will adapt the device to operate at the simulation conditions to approach the predicted optimal performance
- Performing <u>sequential runs</u> with solutions of just semiconductors may yield specific (n,m) chirality enrichment

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 - Noe Alvarez
 - Howard Schmidt
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 - Prof. Robert Hauge
 - Carter Kittrel



Howard Schmidt



Manuel J. Mendes

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- Laura McJilton
- Nick Parra-Vazquez
- Neeraj Rohilla
- * Paul Cherukuri



Noe Alvarez



Backup Slides

SWNT STRUCTURE AND TYPES



* Chiral vector: $C_h = n a_1 + m a_2$

Metallic tubes have <u>n-m=3i</u>, i=integer

* As produced HipCo SWNTs exhibit > 50 (n,m) chiralities

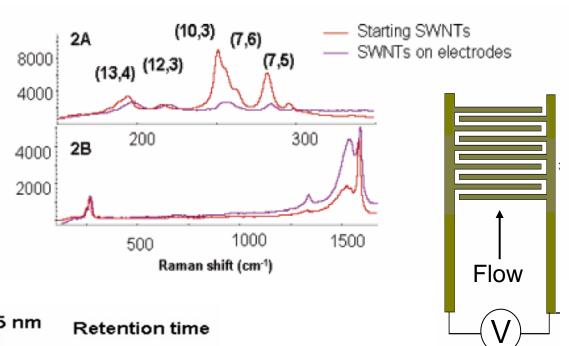
Equidistribution of Chiralities: 1/3 are metallic tubes and 2/3 are semiconductors

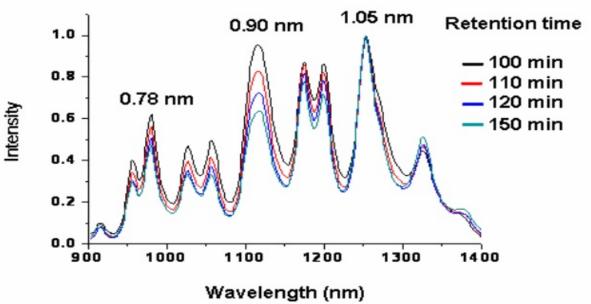
Ref: Bachilo et al. Science, 2002

DIELECTROPHORESIS SO FAR AT RICE



 Bottom of the chamber filled with a Au gold array of 2x50μm electrodes with a 50μm spacing





• 70% type enrichment achieved with DEP-Field Flow Fractionation (FFF)

Ref: Haiqing Peng et al. JACS, 2006

CLAUSIUS-MOSSOTTI FACTOR



Known Values:

$$\bullet \quad \varepsilon_{S} = 5 \ \varepsilon_{0}$$

$$\bullet$$
 $\epsilon_{\rm M} = 10^4 \epsilon_{\rm O}$

$$\bullet$$
 $\epsilon_{\rm m} = 80 \epsilon_{\rm 0}$

$$-\sigma_{\rm m} = 10^{-3} \, \rm S/m$$

$$\mathbf{F}^{DEP} = \frac{V_{NT}}{2} \epsilon_m Re \left[K \right] \nabla E^2$$

$$K^{\perp,//} = \frac{\epsilon_{NT}^* - \epsilon_m^*}{\epsilon_{NT}^* + (\epsilon_{NT}^* - \epsilon_m^*) L^{\perp,//}} \quad \epsilon^* = \epsilon - i \frac{\sigma}{2\pi f}$$

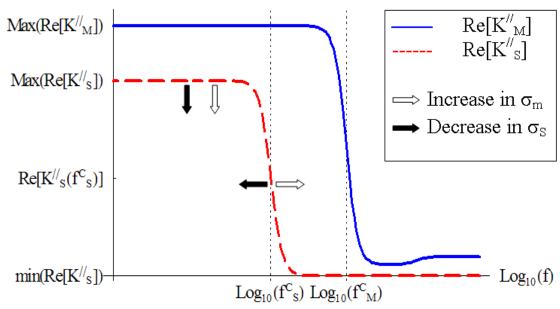
Estimated values:

$$f_S^c = 1 Mhz : \sigma_S = 10^2 S/m$$

•
$$f \sim f_S^c$$
: Re[K_M]=Max(Re[K_M])
 $\sigma_M = 10^5$ S/m

Results will only be function of the separation ratio set by changing f around f_s^c

$$S_{MS} = \frac{Re\left[K_M^{//}\right]}{Re\left[K_S^{//}\right]}$$



Effect of Surfactants on SWNTs K factor

Ref: Ralph Krupke et al. Nano Lett., 2004

MIXTURES OF ANIONIC (-) AND CATIONIC (+) SURFACTANTS



- * Objective: Reduce the SWNT Surface σ to achieve better separation performance at the MHz range
- * Anionic and Cationic mixtures don't have good stability when heated up to 80-100 °C
- Different mixtures were tried with several volume ratios using:
 - ➤ NaCh (-)
 - ➤ CTAB (+)
 - ➤ SDBS (-)
 - **>** SDS (-)
- The combinations that showed best stability under heating are displayed on the graph

